

GP3842

HIGH PERFORMANCE CURRENT MODE CONTROLLERS

Description

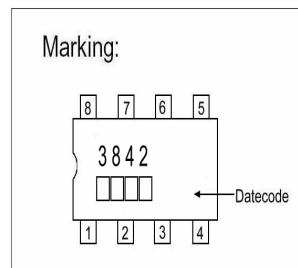
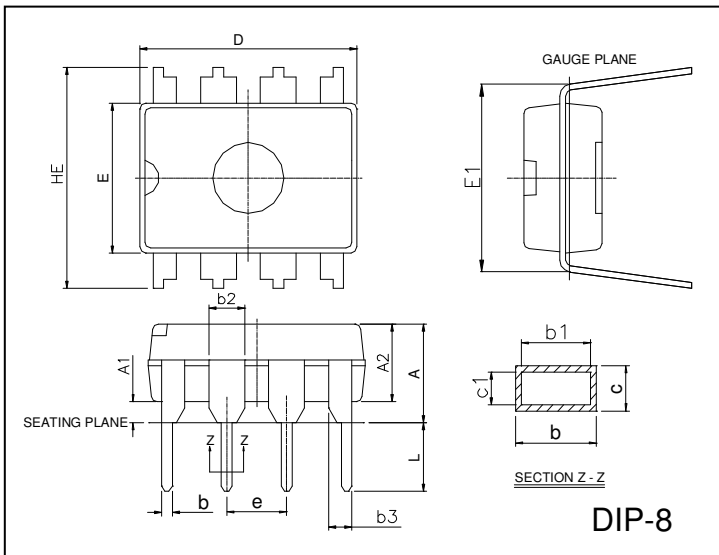
The GP3842 is high performance fixed frequency current mode controllers. This is specifically designed for Off-Line and DC TO DC converter applications offering the designer a cost-effective solution with minimal external components.

These integrated circuits feature a trimmed oscillator for precise duty cycle control. A temperature compensated reference, high gain Error amplifier, current sensing comparator, and a high current totem pole output ideally suited for driving a power MOSFET. Also Included are protective features consisting of input and reference undervoltage lockouts each with hysteresis, cycle-by-cycle current limiting, programmable output deadtime, and latch for single pulse metering.

Features

- *Trimmed Oscillator for Precise Frequency Control
- *Oscillator Frequency Guaranteed at 250kHz
- *Current Mode Operation to 500kHz
- *Automatic Feed Forward Compensation
- *latching PWM for Cycle-By-Cycle Current Limiting
- *Internally Trimmed Reference with Undervoltage Lockout
- *High Current Totem Pole Output
- *Undervoltage Lockout with Hysteresis
- *Low Startup and Operating Current

Package Dimensions



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	-	0.5334	c1	0.203	0.279
A1	0.381	-	D	9.017	10.16
A2	2.921	4.953	E	6.096	7.112
b	0.356	0.559	E1	7.620	8.255
b1	0.356	0.508	e	2.540 BSC	
b2	1.143	1.778	HE	-	10.92
b3	0.762	1.143	L	2.921	3.810
c	0.203	0.356			

DIP-8L	Function	Description
	Pin1: Compensation	This pin is the Error Amplifier output and is made available for loop compensation.
	Pin2: Voltage Feedback	This is the inverting input of the Error Amplifier. It's normally connected to the Switching power supply output through a resistor divider.
	Pin3: Current Sense	A voltage proportional to inductor current is connected to this input. The PWM uses this information to terminate the output switch conduction.
	Pin4: RT/CT	The oscillator frequency and maximum output duty cycle are programmed by connecting resistor RT to Vref and capacitor CT to ground. Operation 500kHz is possible.
	Pin5: Ground	This pin is the combined control circuitry and power ground.
	Pin6: Output	This output directly drives the gate of a power MOSFET. Peak currents up to 1 A are sourced and sunk by this pin.
	Pin7: Vcc	This pin is the positive supply of the control IC.
	Pin8: Vref	This is the reference output. It provides charging current for capacitor CT through resistor RT.

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	VALUE	Unit
Total power Supply and Zener current	(ICc+Iz)	30	mA
Output current, source or sink(note1)	Io	1.0	A
Output energy(capacitive load per cycle)	W	5.0	μJ

Current sense and voltage feedback inputs	Vin	-0.3 to 5.5	V
Error Amplifier Output Sink Current	Io	10	mA
Power Dissipation at Thermal characteristics	PD PθJA	702 178	mW °C/W
Storage Temperature Range	Tstg	-65 to 150	°C
Operating Junction Temperature	TJ	+150	°C
Operating ambient Temperature	TA	0~+70	°C

Electrical Characteristics

(0°C ≤ TA ≤ 70°C, Vcc=15V [note 2], RT=10k, CT=3.3nF, unless otherwise specified)

Parameter	SYMBOL	Test Conditions	Min	Typ.	Max.	Unit
Reference Section						
Output Voltage	VREF	Tj=25°C, Io=1mA	4.90	5	5.1	V
Line Regulation	Regline	Vcc=12V to 25V		2.0	20	mV
Load Regulation	Regload	Io=1mA to 20mA		3.0	25	mV
Temperature Stability	Ts			0.2	-	mV/°C
Total Output Variation	VREF	Line, Load, Temperature	4.82	-	5.18	V
Output Noise Voltage	Vn	F=10kHz to 10Hz, Tj=25°C	-	50	-	μV
Long Term Stability	S	TA=125°C, 1000Hrs	-	5	-	mV
Output Short Circuit current	ISC		-30	-85	-180	mA
Oscillator Section						
Frequency		Tj=25°C	49	52	55	KHz
		TA=0°C to 70°C	48		56	
		Tj=25°C (RT=6.2k, CT=1.0nF)	225	250	275	
Frequency Change with Voltage	Δfosc/ΔV	Vcc=12V to 25V		0.2	1.0	%
Frequency Change with Temperature	Δfosc/ΔT	TA = 0°C to 70 °C		0.5		%
Oscillator Voltage Swing(Peak to Peak)	VOOSC			1.6		V
Discharge Current	Idischg	Tj=25°C TA = 0°C to 70°C	7.8 7.6	8.3	8.8 8.8	mA
Error Amplifier Section						
Voltage Feedback Input	VFB	Vo =2.5V	2.42	2.50	2.58	V
Input Bias Current	IIB	VFB=5.0V		-0.1	-2.0	μA
Open Loop Voltage Gain	AVOL	Vo=2V to 4V	65	90		dB
Unity Gain Bandwidth	BW	Tj=25°C	0.7	1.0		MHz
Power Supply Rejection Ratio	PSRR	Vcc=12V to 25V	60	70		dB
Output Sink Current	Isink	Vo=1.1V, VFB=2.7V	2.0	12		mA
Output Source Current	Isource	Vo=5.0V, VFB=2.3V	-0.5	-1.0		mA
Output Voltage Swing High State	VoH	VFB=2.3V, RL=15K to GND	5.0	6.2		V
Output Voltage Swing Low State	VoL	VFB=2.7V, RL=15K to Vref		0.8	1.1	V
Current Sense section						
Current Sense Input Voltage gain	Av	(Note 3,4)	2.85	3.0	3.15	V/V
Maximum Current Sense Input Threshold	Vth	(Note 3)	0.9	1.0	1.1	V
Power Supply Rejection Ratio	PSRR	Vcc= 12 to 25V (Note 3)		70		dB
Input Bias Current	IIB			-2	-10	μA
Propagation Delay	Tplh(in/out)	Current Sense Input to Output		150	300	ns
Output Low Voltage	VoL	Isink=20mA		0.1	0.4	V
		Isink=200mA		1.6	2.2	V
Output High Level	VoH	Isource=20mA	13	13.5		V
		Isource=200mA	12	13.4		V
Output Voltage with UVLO Activated	VoL (UVLO)	VCC=6.0V, Isink=1.0mA		0.1	1.1	V
Output Voltage Rise Time	tr	Tj=25°C, CL=1nF		50	150	ns
Output Voltage Fall Time	tr	Tj=25°C, CL=1nF		50	150	ns

Under-Voltage Lockout Section						
Startup Threshold	V _{th}		14.5	16	17.5	V
Min. Operating Voltage After Turn-on(V _{CC})	V _{CC(min)}		8.5	10	11.5	V
PWM Section						
Maximum Duty Cycle	DC(MAX)		94	96		%
Minimum Duty Cycle	DC(MIN)				0	%
Total Device						
Power Startup Supply Current	I _{CC+IC}	V _{CC} =14V		0.3	0.5	mA
Power Operating Supply Current	I _{CC+IC}	Note 2		12	17	mA
Power Supply Zener Voltage	V _Z	I _{CC} =25mA	30	36		V

Note 1: Maximum Package power dissipation limits must be observed.

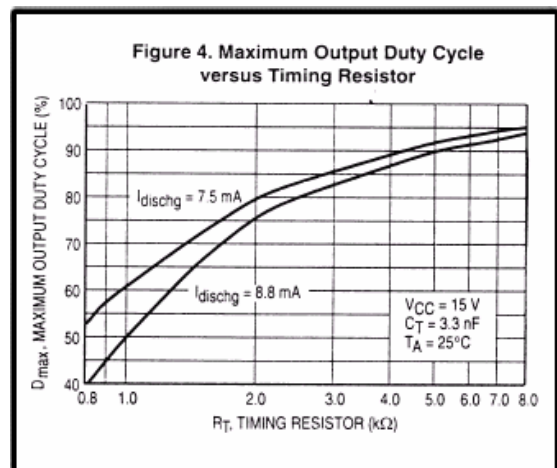
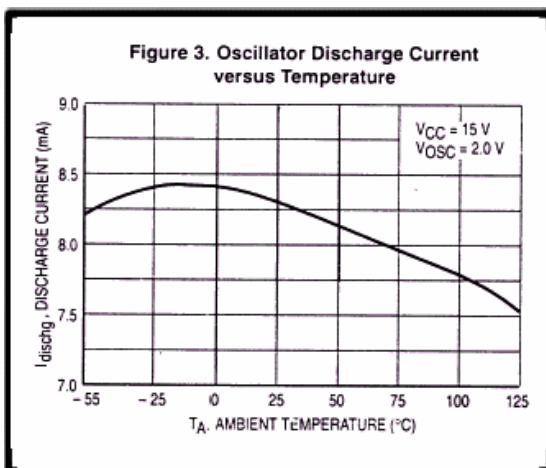
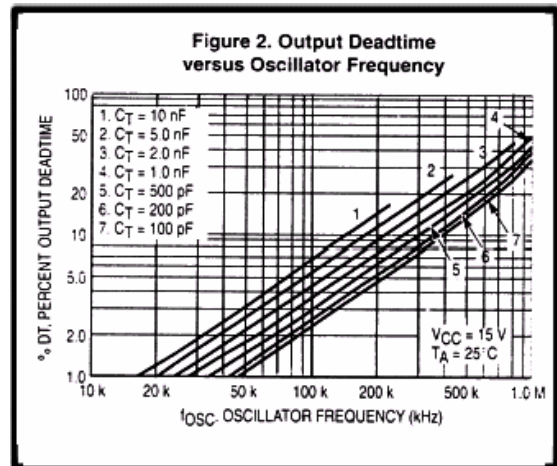
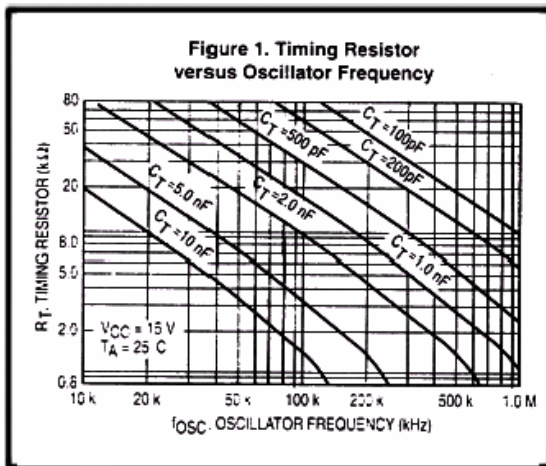
Note 2: Adjust V_{CC} above the Startup threshold before setting to 15V.

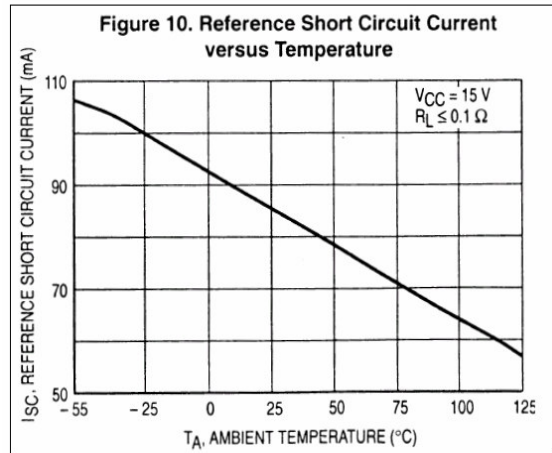
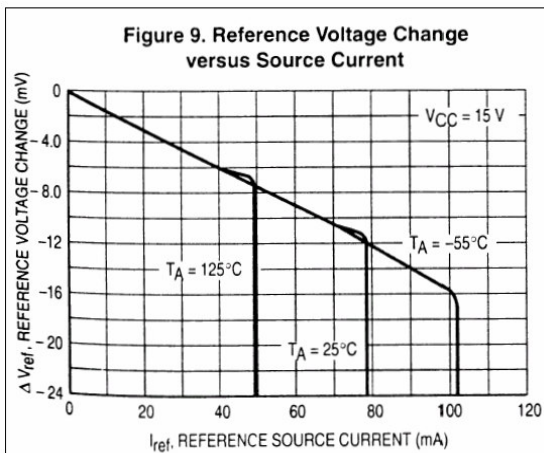
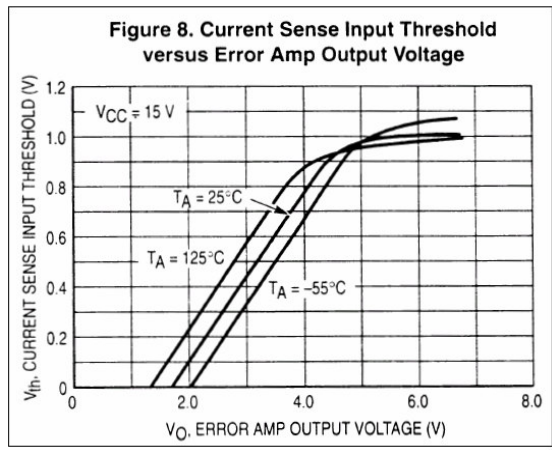
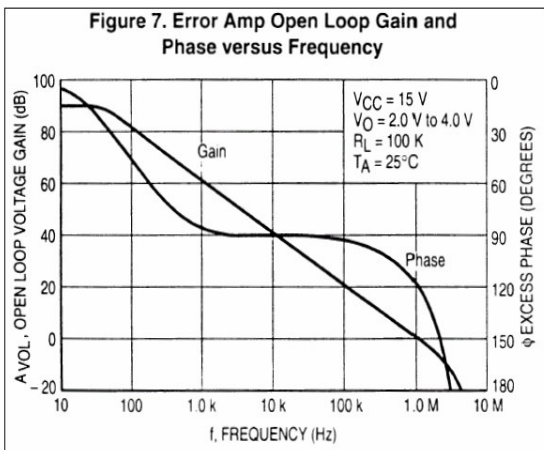
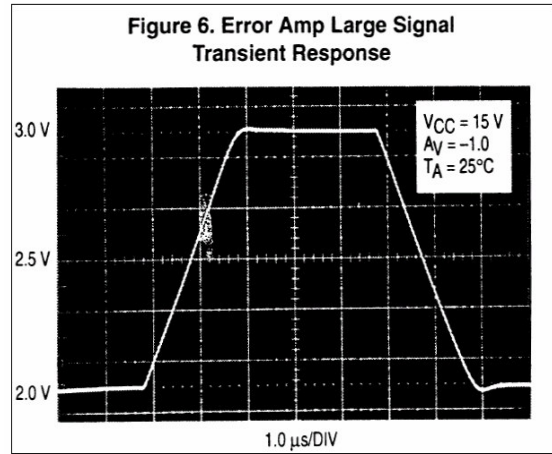
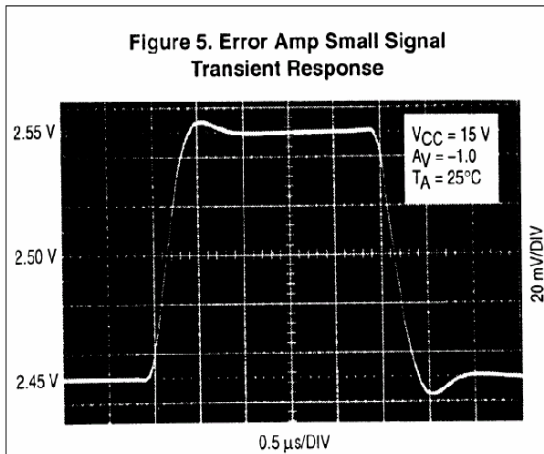
Note 3: This parameter is measured at the latch trip point with V_{Fb}=0V.

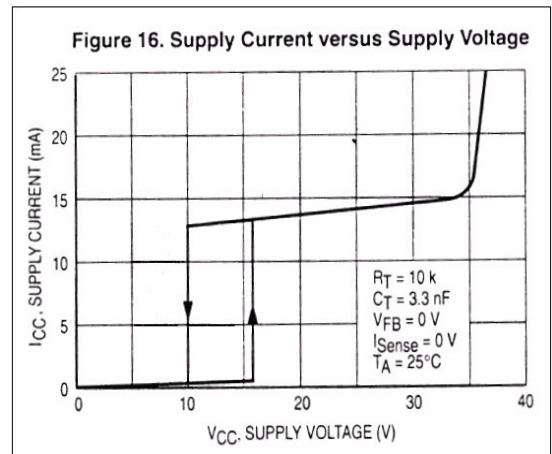
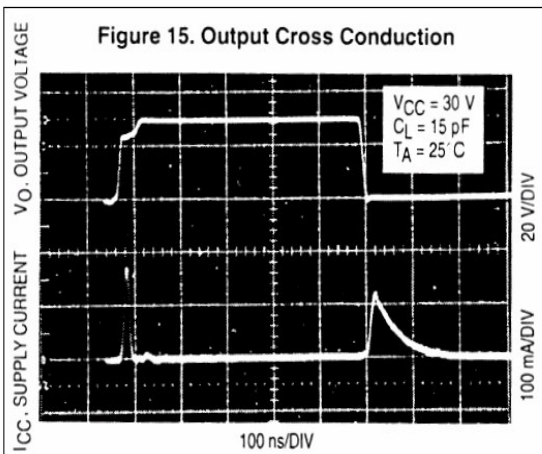
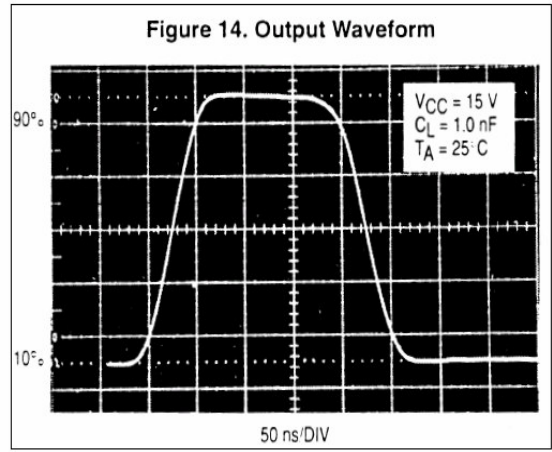
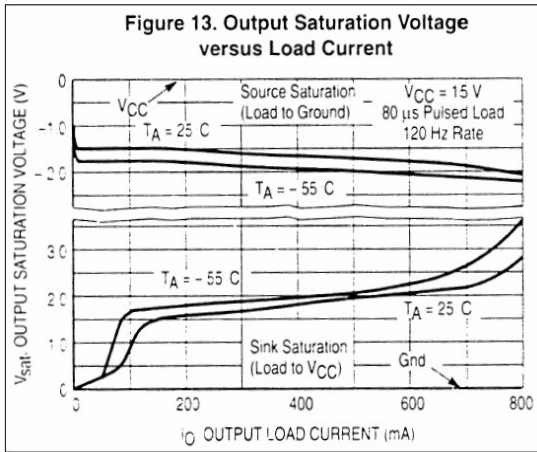
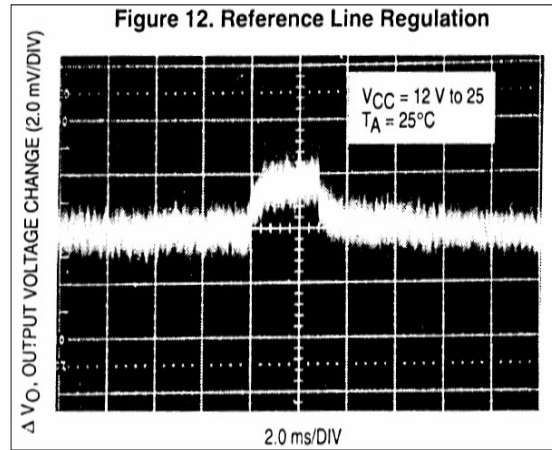
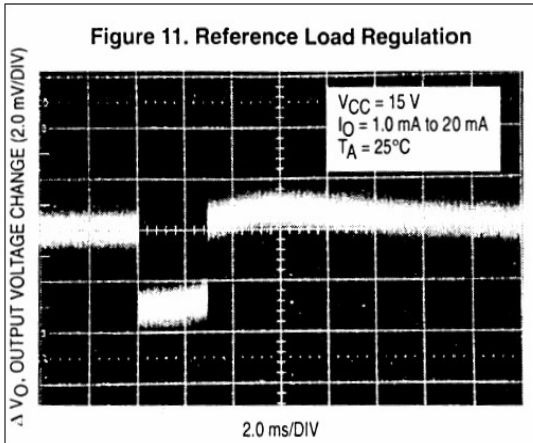
Note 4: Comparator gain is defined as::

$$AV = \frac{\Delta V \text{ Output Compensation}}{\Delta V \text{ Current Sense Input}}$$

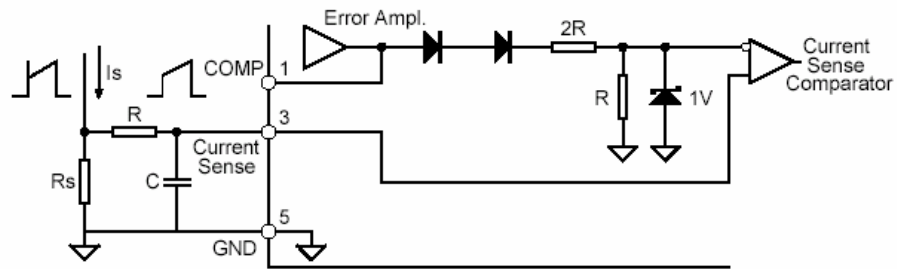
Characteristics Curve





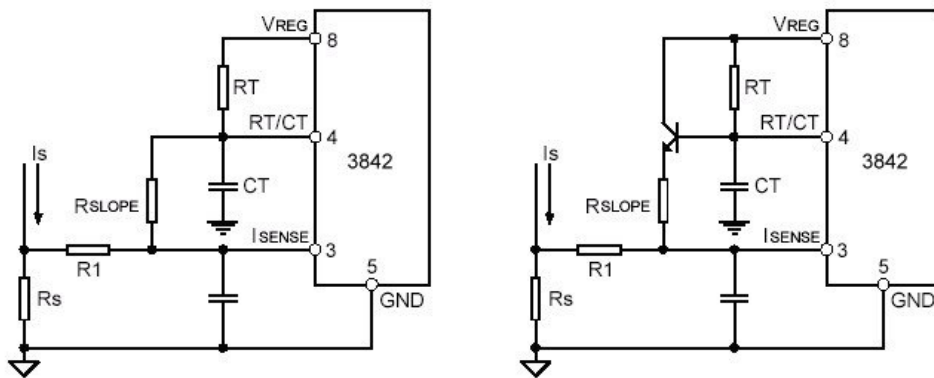


Current Sense Circuit

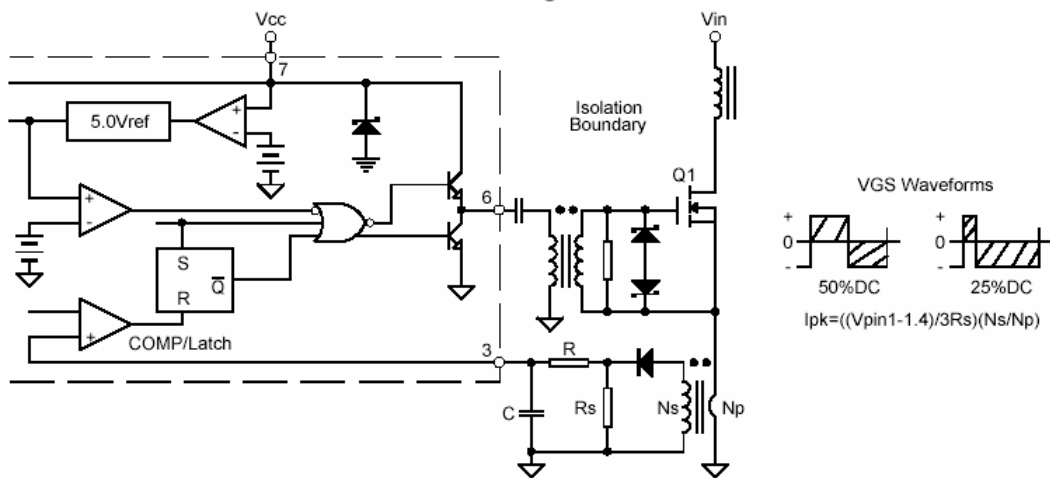


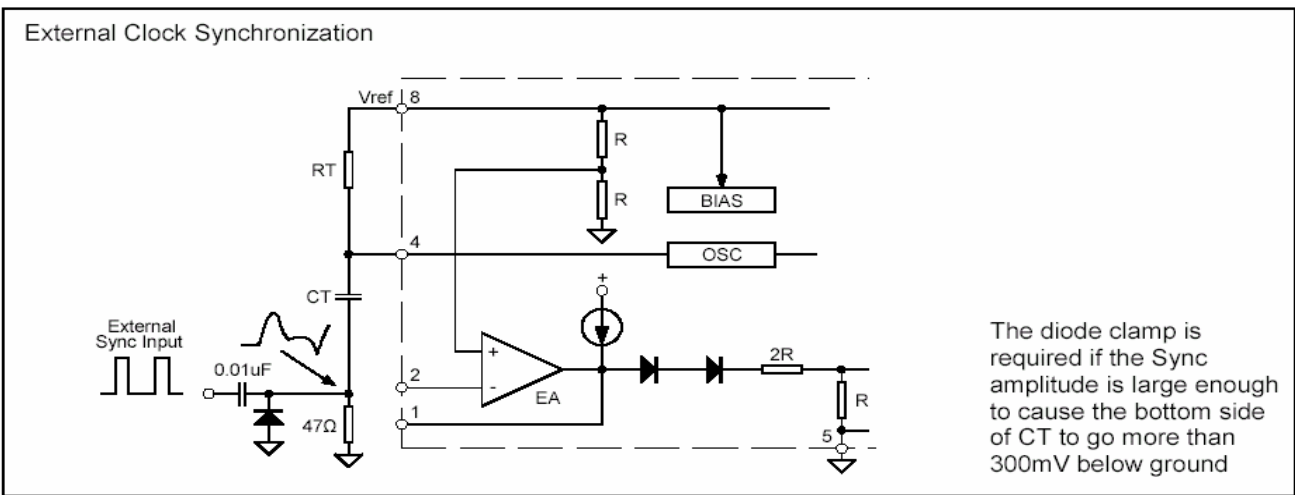
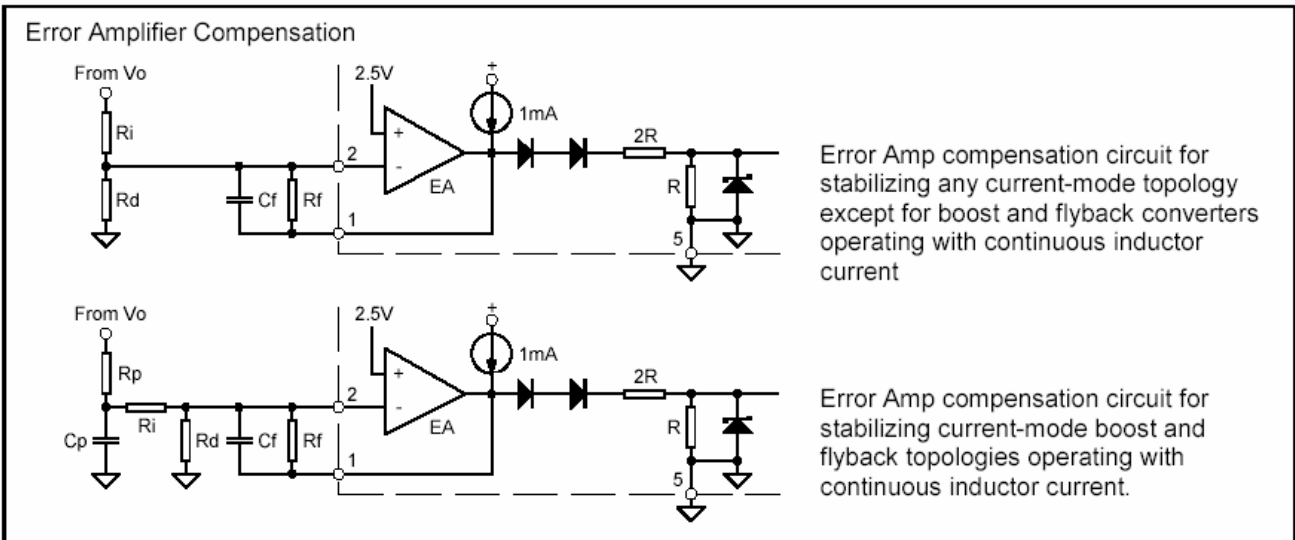
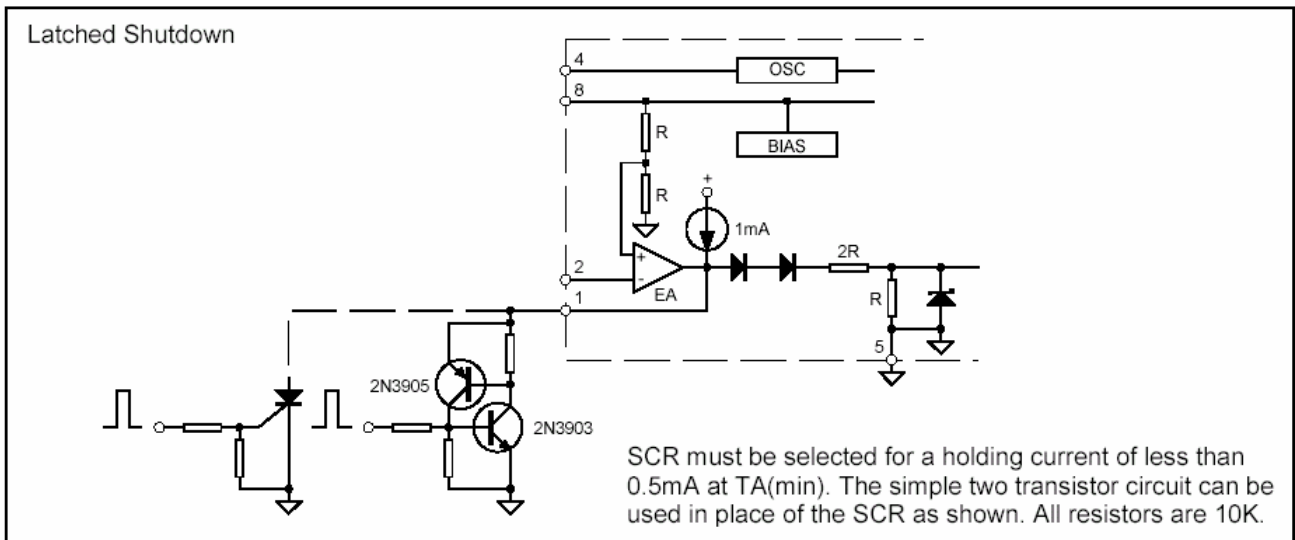
Peak current (I_s) is determined by the formula
 $I_s(\text{max.}) \approx 1V/R_s$
 A small RC filter may be required to suppress switch transients.

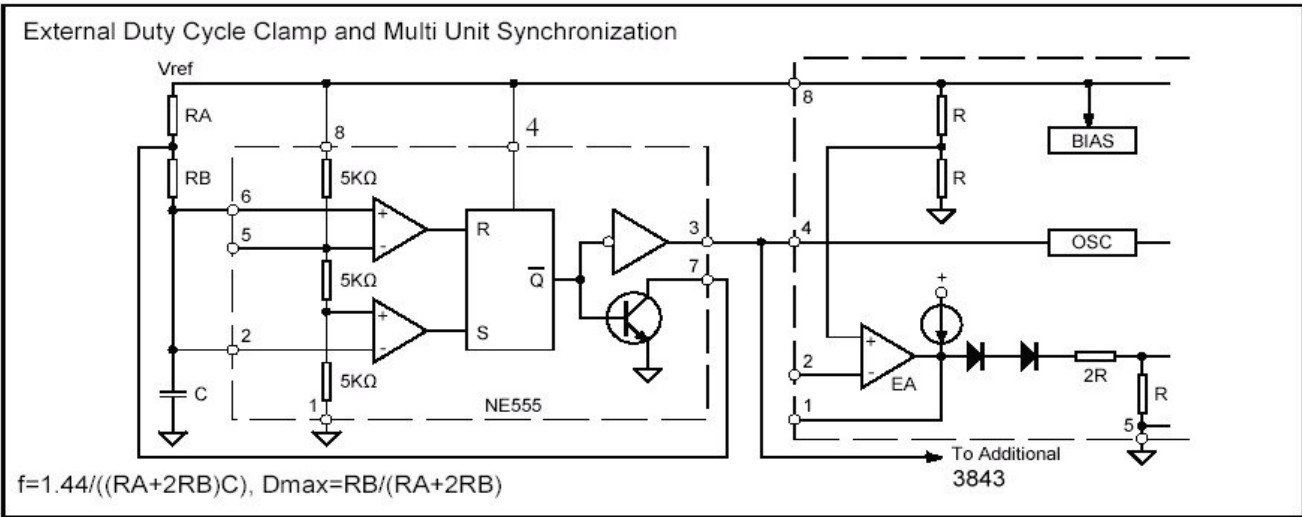
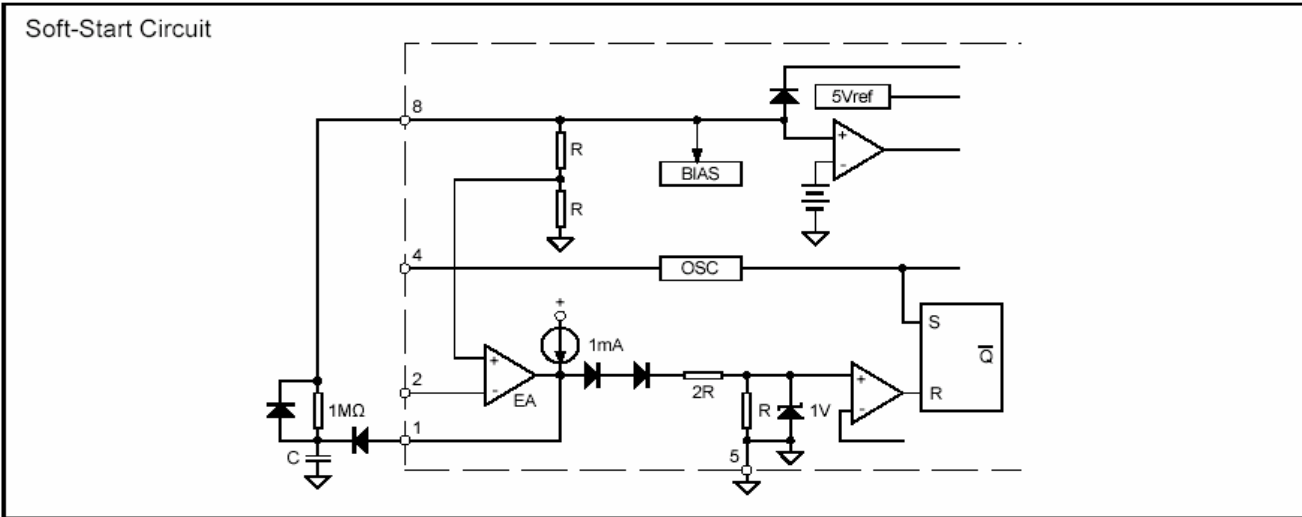
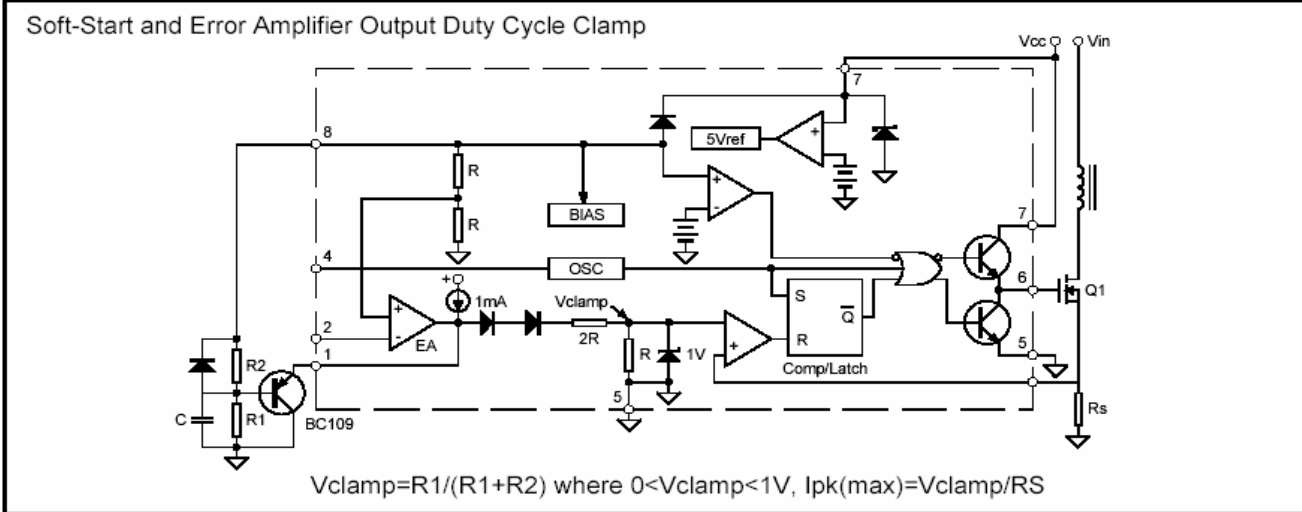
Slope Compensation Techniques



Isolated MOSFET Drive and Current Transformer Sensing







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